Supplementary Figures



Supplementary Figure 1: Na self-diffusivity D_{self} in Na₁₀SiP₂S₁₂, Na₁₀GeP₂S₁₂, and Na₁₀SnP₂S₁₂ from AIMD simulation



Supplementary Figure 2: C222 symmetry ground state ordering of Na atoms for the NMPS phases. Labels on the Na-atoms correspond to those of the $P4_2/nmc$ space group disordered structure.



Supplementary Figure 3: Pseudo-ternary 0K phase diagrams for the a) $Na_2S-SiS_2-P_2S_5$ and b) $Na_2S-GeS_2-P_2S_5$ chemical systems, computed from DFT energy calculations.



Supplementary Figure 4: a) Main peak position for cooling rates of 0.1, 0.2, 0.5, and 1.0 K min⁻¹, and a quenched sample. Lattice volume increases as cooling rate is lowered b). Measured conductivity vs. lattice volume for these samples.



Supplementary Figure 5: Experimental and simulated XRD patterns of quenched $Na_{10}SnP_2S_{12}$.

Supplementary Tables

Compound	$E_{\rm a}~({\rm eV})$	Self diffusivity D_{self} at 298 K (cm ² s ⁻¹)
$Na_{10}SiP_2S_{12}$	0.204	$1.13 imes 10^{-7}$
$Na_{10}GeP_2S_{12}$	0.252	2.97×10^{-8}
$\mathrm{Na_{10}SnP_2S_{12}}$	0.307	6.94×10^{-9}

Supplementary Table 1: Calculated self diffusivity D_{self} of Na₁₀MP₂S₁₂ (M = Si, Sn, Al). Note that the differences between these activation energies and the activation energies of D_{corr} listed in table 1 are not statistically significant.

Cation (M)	a (Å)	c (Å)
Si	9.60	13.53
Ge	9.62	13.59
Sn	9.68	13.63

Supplementary Table 2: DFT calculated lattice parameters for tetragonal $Na_{10}MP_2S_{12}$ (M = Si, Ge, Sn).